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FGH40N120AN 1200V NPT IGBT

Features

- High speed switching
- Low saturation voltage : V_{CE(sat)} = 2.6 V @ I_C = 40A
- High input impedance
- RoHS complaint

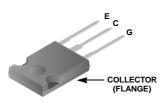
Applications

Induction Heating, UPS, AC & DC motor controls and general purpose inverters.



Description

Employing NPT technology, Fairchild's AN series of IGBTs provides low conduction and switching losses. The AN series offers an solution for application such as induction heating (IH), motor control, general purpose inverters and uninterruptible power supplies (UPS).



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Absolute Maximum Ratings

Symbol	Parameter		FGH40N120AN	Units	
V _{CES}	Collector-Emitter Voltage		1200	V	
V _{GES}	Gate-Emitter Voltage		±25	V	
I _C	Collector Current	@T _C = 25°C	64	А	
	Collector Current	@T _C = 100°C	40	А	
I _{CM(1)}	Pulsed Collector Current		160	А	
P _D	Maximum Power Dissipation	@T _C = 25°C	417	W	
	Maximum Power Dissipation	@T _C = 100°C	167	W	
SCWT	Short Circuit Withstand Time, $V_{CE} = 600V$, $V_{GE} = 15V$, $T_C = 125^{\circ}C$		10	μs	
TJ	Operating Junction Temperature		-55 to +150	°C	
T _{STG}	Storage Temperature Range		-55 to +150	°C	
Τ _L	Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 seconds		300	°C	

Notes:

(1) Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction-to-Case		0.3	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction-to-Ambient		40	°C/W

		king Device Pae		ckage Reel Size 0-247 -		e Width	Qua	antity
		TO-247	-			30		
Electrica	al Char	acteristics of the	IGBT T _c =	25°C unless otherwise not	ed			
Symbol		Parameter	Co	onditions	Min.	Тур.	Max.	Units
Off Charact	eristics							
BV _{CES}	Collector	-Emitter Breakdown Voltag	e V _{GE} = 0V,	$V_{GE} = 0V, I_C = 1mA$				V
BV _{CES} / ΔT _J	Temperature Coefficient of Breakdown Voltage		vn V _{GE} = 0V,	$V_{GE} = 0V, I_C = 1mA$		0.6		V/°C
I _{CES}	Collector	Cut-Off Current	$V_{CE} = V_{CE}$	_{ES} , V _{GE} = 0V			1	mA
I _{GES}	G-E Leal	kage Current	$V_{GE} = V_{GI}$	$ES, V_{CE} = 0V$			±250	nA
On Charact	eristice							
V _{GE(th)}		eshold Voltage	I _C = 250μ	A, V _{CE} = V _{GE}	3.5	5.5	7.5	V
02(11)		Collector to Emitter Saturation Voltage		$I_{\rm C} = 40$ A, $V_{\rm GE} = 15$ V		2.6	3.2	V
Vor($I_{C} = 40A, V_{GE} = 15V,$ $T_{C} = 125^{\circ}C$		2.9		V
			I _C = 64A,	I _C = 64A, V _{GE} = 15V		3.15		V
Dynamic Cl	haracteris	tics				1		-
C _{ies}	Input Ca	Input Capacitance		V _{CE} = 30V, V _{GE} = 0V f = 1MHz		3200		pF
C _{oes}	Output Capacitance Reverse Transfer Capacitance					370		pF
c _{res}						125		pF
Switching (Characteri	stics						
t _{d(on)}	Turn-On Delay Time					15		ns
t _r	Rise Tim	е		V _{CC} = 600V, I _C = 40A,		20		ns
t _{d(off)}	Turn-Off	Delay Time	$V_{CC} = 600$			110		ns
t _f	Fall Time)	R _G = 5Ω,	V _{GE} = 15V,		40	80	ns
Eon	Turn-On	Switching Loss	Inductive	Inductive Load, $T_C = 25^{\circ}C$		2.3	3.45	mJ
E _{off}	Turn-Off	Switching Loss		-		1.1	1.65	mJ
E _{ts}	Total Swi	tching Loss				3.4	5.1	mJ
t _{d(on)}	Turn-On	Delay Time				20		ns
t _r	Rise Tim	e				25		ns
t _{d(off)}	Turn-Off	Delay Time	V _{CC} = 600)V, I _C = 40A,		120		ns
t _f	Fall Time		R _G = 5Ω,	$R_G = 5\Omega$, $V_{GE} = 15V$, Inductive Load, $T_C = 125^{\circ}C$		45		ns
E _{on}	Turn-On	Switching Loss	inductive			2.5		mJ
E _{off}	Turn-Off	Switching Loss]		1.8		mJ
E _{ts}	Total Swi	tching Loss				4.3		mJ
Qg	Total Gat	e charge	V 600	$1/1_{-} = 40.0$		220		nC
Q _{ge}	Gate-Em	itter Charge	V _{CE} = 600 V _{GE} = 15\	IV, I _C = 40A, /		25		nC
Q _{gc}	Gate-Co	lector Charge	JL I			130		nC

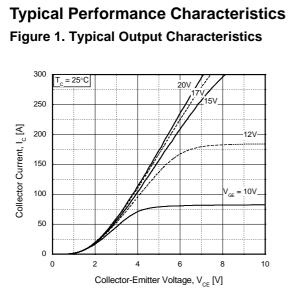


Figure 3. Saturation Voltage vs. Case Temperature at Variant Current Level

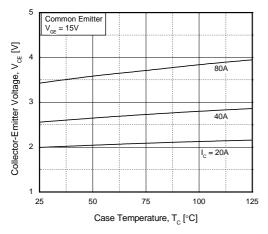


Figure 5. Saturation Voltage vs. V_{GE}

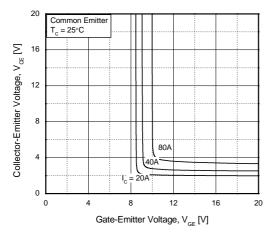


Figure 2. Typical Saturation Voltage Characteristics

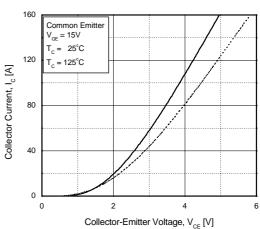


Figure 4. Load Current vs. Frequency

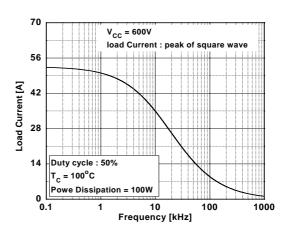
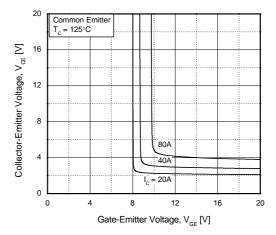


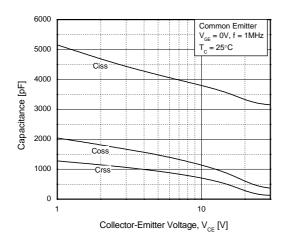
Figure 6. Saturation Voltage vs. V_{GE}



FGH40N120AN 1200V NPT IGBT

Typical Performance Characteristics (Continued)







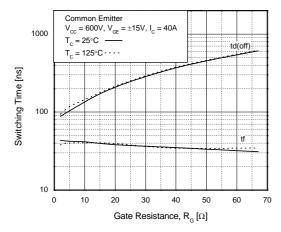


Figure 11. Turn-On Characteristics vs. Collector Current

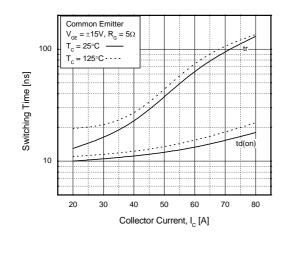


Figure 8. Turn-On Characteristics vs. Gate Resistance

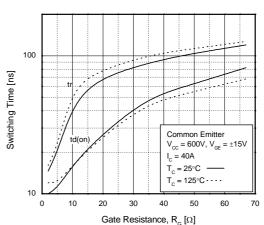


Figure 10. Switching Loss vs. Gate Resistance

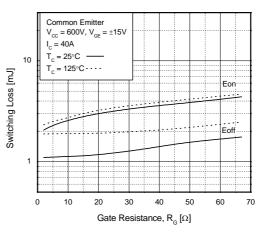
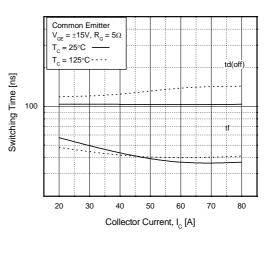
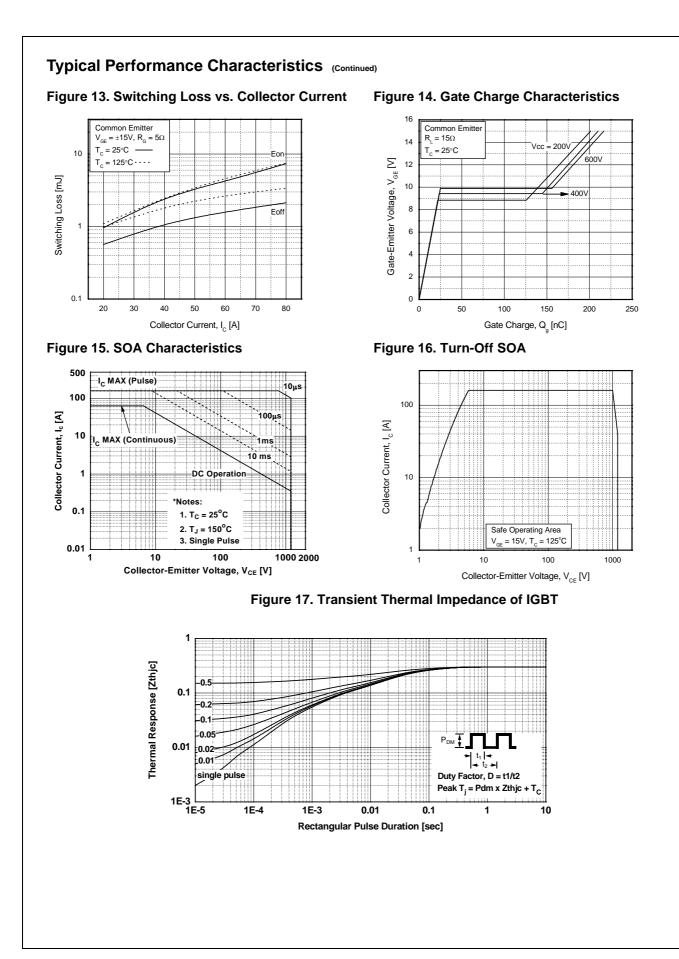
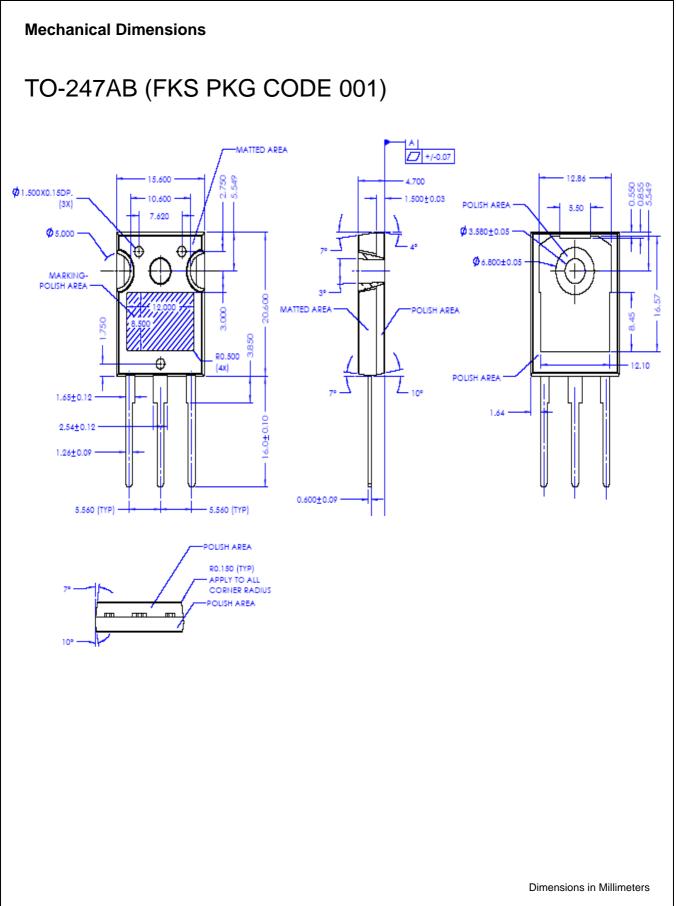


Figure 12. Turn-Off Characteristics vs. Collector Current









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